

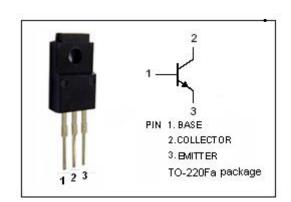
isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Base Breakdown Voltage-
- : V_{(BR)CBO}= 500V(Min.)
- Wide Area of Safe Operation
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

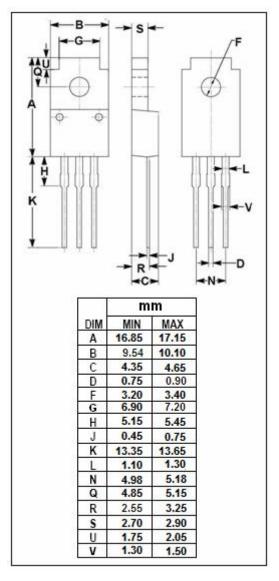


· Designed for high speed switching applications.



ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	500	V	
V _{CES}	Collector-Emitter Voltage	500	V	
V _{CEO}	Collector-Emitter Voltage	400	V	
V _{EBO}	Emitter-Base Voltage	7	V	
Ic	Collector Current-Continuous	5	Α	
Ісм	Collector Current-Peak	10	Α	
lΒ	Base Current-Continuous	1.5	А	
P _C	Collector Power Dissipation @Ta=25℃	2	· W	
	Collector Power Dissipation @T _C =25°C	35		
T _j	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	





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2SC4026

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

Ic=25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	400			V			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 0.4A			1.0	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 2A; I _B = 0.4A			1.5	V			
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			100	μА			
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μА			
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	15						
h _{FE-2}	DC Current Gain	I _C = 2A; V _{CE} = 5V	8						
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 10V; f= 1MHz		5		MHz			
Switching Times									
ton	Turn-on Time				0.7	μS			
ts	Storage Time	I _C = 2A; I _{B1} = 0.4A; I _{B2} = -0.8A; V _{CC} = 150V			2.0	μS			
t _f	Fall Time				0.3	μS			

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